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⑳ Applicant: FUJITSU LIMITED  
1015, Kamikodanaka Nakahara-ku  
Kawasaki-shi Kanagawa 211(JP)

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㉒ Inventor: TAKAHASHI, Yoshio  
5093-6, Kaminagaya-cho  
Konan-ku, Yokohama-shi Kanagawa 233(JP)

㉓ Designated Contracting States:  
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㉔ Representative: Reinländer & Bernhardt  
Patentanwälte et al,  
Orthstrasse 12  
D-8000 München 60(DE)

㉕ **THIN-FILM COIL PRODUCING METHOD.**

㉖ A method for producing a thin-film coil involves first the making of a flat coil layer in which counterpart spiral conductor patterns having the same winding direction are fitted together so as to obtain adjacent whorls (11, 16), secondly the making of a further flat coil layer in a similar way so as to obtain adjacent whorls (28, 40) wound in the opposite direction, and then placing the second flat coil layer on the first. The conductor patterns of the first layer are individually connected to the conductor pattern of the second layer so as to make up a coil.

Fig. 3A

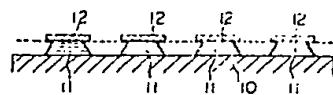
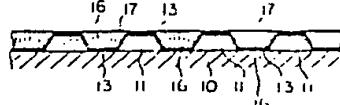


Fig. 3D



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## DESCRIPTION

## TECHNICAL FIELD

5 The present invention relates to a process for the preparation of film coils for use in, for example, thin-film magnetic heads, utilizing the technique of photolithography, and more particularly, the invention relates to a process for the preparation of a flattened multi-layer 10 multi-winding conductor coil.

## BACKGROUND ART

In forming a multi-layer pattern structure on the surface of a semiconductor in the field of semiconductor integrated circuits, there has heretofore been adopted a 15 method in which patterns of respective layers are laminated in sequence from a lower layer to a higher layer according to the ordinary photolithographic technique. In this method, if a layer is not a flat but includes convexities and concavities, corresponding convexities and concavities 20 are formed in the layers laminated thereon. Accordingly, the flatness of the topmost layer is influenced by the convexities and concavities of all the layers and, even if the convexities and concavities of the respective layers 25 are small, the flatness of the topmost layer is considerably degraded. When another pattern layer is formed on a certain layer through a photomask, the presence of such convexities and concavities results in a non-uniformity of the gap between the photomask and the layer surface, and therefore, the precision of the pattern is drastically 30 lowered.

This problem of degradation of the flatness has a close relationship to the subject matter of the present invention. Accordingly, this problem will now be described in detail by reference to a case of a film coil for use in 35 a thin-film magnetic head.

In a conventional thin-film magnetic head, as

illustrated in Fig. 1, a lower magnetic layer 2 is formed on a substrate 1, and an upper magnetic layer 4 is formed thereon. A coil 3 is interposed between the layers 2 and 4. Further, a gap 5 for generating a leakage magnetic field for writing and reading is formed between these magnetic layers 2 and 4. In principle, as illustrated in Fig. 2, such a coil 3 is formed by forming a first layer conductor pattern 6 having a spiral shape according to the photolithographic technique, piling a second layer conductor pattern 7 on the first layer conductor pattern 6 with the interposition of insulating layer therebetween, not illustrated in the drawing, connecting one of the ends of these conductor patterns to each other by means of a conductor exposing window 8 formed by etching the insulating layer on the lower layer pattern 6, and forming conductor exposing windows 6A and 7A for connection of a cable on the other ends of the conductor patterns 6 and 7.

Similar procedures to those described above are repeated according to the number of conductor layers to be laminated, and as the number of conductor layers to be laminated is increased, the number of lower layer conductor exposing windows should be increased. More specifically, in case of an n-layer structure, (n-1) windows should be formed. Accordingly, the number of steps in the forming operation is increased and the efficiency of the operation is reduced. Further, when the first conductor layer 6 is formed and the second conductor layer 7 is formed thereon with the interposition of the insulating layer therebetween, a stepped portion is formed between the portion where the second layer conductor 7 is piled on the first layer conductor 6 and the portion where the second layer conductor 7 is not piled on the first layer conductor 6. More specifically, a stepped portion is formed in an area 9 where the first layer conductor 6 does not exist (such area is inevitably present) when the second layer conductor 7 is formed.

Ordinarily, in photolithography, if there is

present a stepped portion, the thickness of the resulting resist film in this portion is different from the thickness in the other portion, and as is well-known, a stress imposed on the conductor film in such stepped portion 5 causes various troubles in formation of the pattern. For example, if the thickness of the film conductor pattern 7 formed in the stepped portion is reduced, an increase of the resistance value of the conductor is caused, and in the worst case, breaking is caused to occur. According to 10 photolithography, ordinarily, a resist is spin-coated and then subjected to exposure and development, and the resist is thick at the concave part of the above-mentioned stepped portion but is thin at the convex part. Therefore, uniform exposure conditions cannot be attained, and practically it 15 is substantially impossible to form a multi-layer fine and delicate pattern according to photolithography.

#### DISCLOSURE OF THE INVENTION

In view of the above mentioned circumstances, a primary object of the present invention is to provide a 20 process for the preparation of thin-film multi-winding coils in which a multi-layer conductor pattern can be formed on one plane with a high flatness in the resulting coil.

According to the present invention, this object can 25 be attained by forming a first layer conductor pattern having a spiral shape, forming a second layer conductor pattern of a similar spiral shape in the gap portion of the first layer conductor pattern on the same plane as that of the first layer conductor pattern, thereby to form 30 a first plane coil layer, and laminating a similarly formed second plane coil layer which is different from the first plane coil layer in the direction of its spiral, on the first plane coil layer.

#### BRIEF EXPLANATION OF DRAWINGS

35 Fig. 1 is a perspective view illustrating a typical instance of the conventional thin-film magnetic head.

Fig. 2 is a perspective view illustrating,

diagrammatically, a film coil for use in the thin-film magnetic head shown in Fig. 1.

Figs. 3A to 3D are views illustrating the steps of flattening a two-layer conductor pattern according to the present invention.

Fig. 4A to 4F are views illustrating the steps of flattening a three-layer conductor pattern according to the present invention, and Fig. 4E' is a view illustrating a modification of the step shown in Fig. 4E.

Figs. 5A-(a) to 5A-(c) are views illustrating the conventional etching process, and Figs. 5B-(a) to 5B-(c) are views illustrating the taper etching process.

Fig. 6A to 6C are views illustrating the flattening of conductor patterns according to the taper etching process.

Figs. 7A-(a) to 7A-(e) are views illustrating the steps of the process for preparing a multi-winding coil according to the present invention, and Figs. 7B-(a) to 7B-(e) are sectional views corresponding to Figs. 7A-(a) to 7A-(e), respectively.

Figs. 8A to 8D are views illustrating the steps of the process for preparing a thin-film magnetic head.

Fig. 9 is a sectional view illustrating a thin-film magnetic head.

Figs. 10A to 10D are views illustrating the steps of the process for preparing a multi-tracks thin-film magnetic head.

Fig. 11A is a view illustrating the state where the step shown in Fig. 10B has been completed, and Fig. 11B is a view illustrating the state where the step shown in Fig. 10D has been completed.

#### BEST MODE FOR CARRYING OUT THE INVENTION

The present invention will now be described in detail with reference to the accompanying drawing.

Referring to Figs. 3A to 3D, a process for flattening two layers of conductor patterns will now be described.

As illustrated in Fig. 3A, a thin-film first layer conductor

Pattern 11 is formed on a substrate 10 by using a photo resist pattern 12 according to an etching technique, such as chemical etching, ion milling or the like, and; then, as illustrated in Fig. 3B, an insulating layer 13 is formed on the entire surface of the first layer conductor pattern 11 according to the sputtering method, the vacuum deposition method or the like. Then, as illustrated in Fig. 3C, a second conductor pattern 16 is formed in a slit portion 14 of the first layer conductor pattern 11 by using a resist pattern 15 according to the etching technique, so that the slit 14 is filled up with the second layer conductor pattern 16. Further, as shown in Fig. 3D, an insulating layer 17 is formed on the entire surface on the second layer conductor pattern 16. By the foregoing procedures, the first layer conductor pattern 11 and the second layer conductor pattern 16 are arranged alternately in the same plane to attain the flattening. If the steps illustrated in Figs. 3A to 3D are repeated on the insulating layer 17, a plurality of flattened conductor patterns can be laminated.

A process for flattening three layers of conductor patterns is illustrated in Figs. 4A to 4F. In the steps illustrated in Figs. 4A to 4D, as in the steps illustrated in Figs. 3A to 3D, a first layer conductor pattern 11, an insulating layer 13, a second layer conductor pattern 16 and an insulating layer 17 are formed in sequence on a substrate 10. Further, as illustrated in Fig. 4E, a slit portion 18 of the first and second layer conductor patterns 11 and 16 is pattern-etched by using a resist pattern 19 to form a third layer conductor pattern 20 filling up the slit portion 18, and as illustrated in Fig. 4F, an insulating layer 21 is formed on the third layer conductor pattern 20. Thus, the three layers of the conductor patterns 11, 16 and 20 are formed on the same plane. When the above procedures are similarly repeated, an optional number of layers of conductor patterns can be flattened and formed on the same plane.

In this case, a flattened multi-layer conductor can be formed by forming two conductors 16A and 16B on the two sides of the first layer, conductor 11 as illustrated in Fig. 4E', and repeating the procedures similarly.

5 The lithographic mechanism for attaining the above-mentioned flattening will now be described specifically. A process for forming thin-film patterns by chemical etching is illustrated in Figs. 5A and 5B. For example, a first layer conductor pattern 11 including a resist pattern 12 is originally formed on a substrate 10 by the etching 10 steps illustrated in Figs. 5A-(a) to 5A-(c). In this process, in connection with the speed of etching at the end portion of the resist pattern 12, the speed  $v_y$  of etching in the direction of the film thickness is higher 15 than the speed  $v_H$  of etching in the direction intruding into the surface boundary of the resist pattern ( $v_y > v_H$ ), and therefore, a relatively steep step 22 is formed in the end portion of the conductor pattern 11 after etching, as illustrated in Fig. 5A-(d). If the property of the surface 20 of the film is changed or the permeability of the etching solution is increased so that the etching speed  $v_H$  in the direction intruding into the surface boundary of the resist pattern is higher than the etching speed  $v_y$  ( $v_y < v_H$ ), a gradual taper 23 is formed in the end portion of the 25 conductor pattern 11 by etching, as illustrated in Figs. 5B-(a) to 5B-(c).

2 Figs. 6A to 6C illustrate a process for flattening two layers of conductor patterns by taper etching (bevel etching). As illustrated in Fig. 6A, a first layer conductor 30 pattern 11 is formed on a substrate 10 with a taper angle of  $\theta$ , and a resist pattern 15 is formed on the first layer conductor pattern 11 through an insulating layer 13 and a second layer conductor pattern 16. In this state, etching is conducted in sequence as illustrated in Figs. 6B and 35 6C, and if the angle  $\theta'$  between the second layer conductor pattern 16 and the resist pattern 15 at the time of completion of etching is equal to the above-mentioned taper

angle  $\theta$  of the first layer conductor pattern 11, a flattened pattern surface, as illustrated in Fig. 6C, can be obtained.

The process for attaining the flattening in the present invention is not limited to the above described 5 bevel etching process and, of course, the customary lift-off method and the like can be adopted in the present invention.

Formation of a multi-winding coil for a thin-film magnetic head by utilizing the process of the present invention will now be described.

10 An embodiment of a five-winding coil including two layers of conductor patterns is illustrated in Figs. 7A and 7B. First, as illustrated in Figs. 7A-(a) and 7B-(a), a first layer conductor pattern 11, having a plane spiral shape of three windings with substantially equal slits, is 15 formed on a substrate 10. As illustrated in Figs. 7A-(b) and 7B-(b), an insulating layer 13 of  $\text{SiO}_2$  or the like is formed on the first layer conductor pattern 11 and a second layer conductor film 16' is then formed on the insulating layer 13. Then, a resist pattern 15 is formed 20 in slits 14 of the spiral shape of the first layer conductor pattern 11, as illustrated in Figs. 7A-(c) and 7B-(c), and when bevel etching is then carried out, a second layer conductor pattern 16, having a spiral shape of two windings, is formed in the slits 14, as illustrated in Figs. 7A-(d) 25 and 7B-(d). Then, the resist pattern 15 is removed and an insulating layer 17 is formed as illustrated in Figs. 7A-(e) and 7B-(e). Thus, the first layer conductor pattern 11 of three windings and the second layer conductor pattern 16 of two windings are flatly formed on the same plane 30 without any pattern crossing.

The process for preparing a thin-film magnetic head by using a multi-winding coil as mentioned above will now be described with reference to Figs. 8A through 8D and Fig. 9. For convenience, an embodiment using a ten-winding 35 coil having four layers of conductor patterns will be described.

A lower magnetic layer 25 (Fig. 9) is formed on a

substrate 24 (Fig. 9) and, according to the process illustrated in Figs. 7A and 7B, a first layer conductor pattern 11 is formed in a spiral shape of three windings in the counterclockwise direction on the lower magnetic layer 25

5 with the interposition of an insulating layer 26 (see Fig. 8A) therebetween. Then, a second layer conductor pattern 16 is formed in an area of a slit 14 in a spiral shape of two windings in the counterclockwise direction with the interposition of an insulating layer 13 therebetween,

10 whereby a first plane coil layer including two layers of conductor patterns with 5 windings is formed (see Fig. 8B). Then, an insulating layer 17 (Fig. 9) is formed on the second layer conductor pattern 16, and window 34, and 35 are formed on the inner end of the first layer conductor

15 pattern 11 and on the outer end of the second layer conductor pattern 16 respectively, to expose the conductor patterns. Then, as illustrated in Fig. 8C, a third layer conductor pattern 28 is formed in a spiral shape of three windings in the clockwise direction, namely the direction reverse

20 to the above spiral direction, at a position substantially in agreement with the position of the first layer conductor pattern 11. Then, an insulating layer 37 (Fig. 9) is formed on the third layer conductor pattern 28, and a window 39 is formed on the inner end portion of the second

25 layer conductor pattern 16 to expose the conductor. Then, a fourth layer conductor pattern 40 is formed in a spiral shape of two windings in the clockwise direction in a slit 36 of the third layer conductor pattern 28, namely an area in agreement with the position of the second layer conductor

30 pattern 16 (see Fig. 8D). By laminating the third and fourth layer conductor patterns 28 and 40 in the foregoing manner, a second plane coil layer including two conductor layers with five windings is constructed. It should be noted that, as illustrated in Fig. 9, an upper magnetic layer 30

35 is formed on a part of the conductor patterns 11, 16, 28 and 40, and a WRITE READ gap 41 is formed between this upper magnetic layer 30 and the lower magnetic layer 25.

When the outer end portions 11A and 40A of the first and fourth layer conductor patterns 11 and 40 are used as terminals for connection of outside wires, the first layer conductor pattern 11 is connected to the third 5 layer conductor pattern 28 by means of the window 34 on the inner end portion thereof, and also, to the second layer conductor pattern 16 by means of the window 35 on the outer end portion of the second layer conductor pattern 16 and to the fourth layer conductor pattern 40 by means 10 of the window 39 on the inner end portion thereof, whereby one continuous coil of 10 windings is constructed. It should be noted that, since the window 35 is located at an intermediate position in the entire structure with respect to the number of windings and the resistance value, when a 15 terminal is attached to the window 35, it can be used as an center tap.

When a third plane coil layer is further formed on the second plane coil layer with the interposition of an insulating layer 46, therebetween windows 44 and 43 are 20 formed on both the inner and outer end portions of the third layer conductor pattern 28, respectively, and a window 45 is formed on the inner end portion of the fourth layer conductor pattern 40.

The number and positions of windows are appropriately determined according to the shapes of the conductor 25 patterns, the number of laminated layers and and the number of laminated plane coil layers. The number of the plane coil layers can optionally be increased by laminating alternately the so formed first and second plane coil 30 layers in succession.

Further, as pointed out hereinbefore, the number of layers of conductor patterns included in each plane coil layer is not limited to two, but three or four layers of conductor patterns may be formed for each plane coil 35 layer. In this case, for example, in the case where each plane coil layer includes three layers of conductor patterns, the conductor patterns are connected in a manner of first

layer (first plane coil layer) —> fourth layer (second plane coil layer) —> second layer (first plane coil layer) —> fifth layer (second plane coil layer) —> third layer (first plane coil layer) —> sixth layer (second plane coil layer), and; in the case where each plane coil layer includes four layers of conductor patterns, the conductor patterns are connected, for example, in a manner of first layer (first plane coil layer) —> fifth layer (second plane coil layer) —> second layer (first plane coil layer) —> sixth layer (second plane coil layer) —> third layer (first plane coil layer) —> seventh layer (second plane coil layer) —> fourth layer (first plane coil layer) —> eighth layer (second plane coil layer). As will be apparent from the foregoing illustration, the first and second plane coil layers are connected to each other alternately.

According to the above-mentioned preparation process, a multi-layer coil structure of multi-windings can be formed on the same plane without crossing among a plurality of layers of conductor patterns, and therefore, the disadvantages involved in the conventional photolithographic technique can be eliminated and a multi-layer multi-winding conductor coil applicable to practical uses can be manufactured. Further, since the entire structure is flattened, the increase of the thickness can be controlled and there can be attained an advantage with respect to durability. Still further, since conductor patterns can be connected to one another through not only the inner end portions but also the outer end portions, it is easy to form center tap. Moreover, since unnecessary convexities and concavities are not formed with the upper magnetic layer when a thin-film magnetic head or the like is constructed by using such conductor coil, advantages can be attained with respect to the efficiency of the magnetic circuit and the structure can be reduced in the size.

The concavity of the window, namely the thickness

of the insulating layer, is very small as compared with the thickness of the conductor pattern, and therefore, no particular disadvantage is caused by the concavity of the window.

5 A method of preparing a multi-tracks thin-film magnetic head by utilizing the above-mentioned process for forming a multi-winding film coil according to the present invention will now be described. For convenience, the following illustration is presented with regard to a  
10 four-tracks magnetic head.

Each magnetic head is prepared according to the process illustrated in Figs. 8A to 8D and has a structure as shown in Fig. 9. In principle, if a predetermined number of thin-film magnetic heads are simultaneously  
15 formed according to such process, there can be constructed a multi-track thin-film magnetic head. In order to avoid formation of a slit between every two adjacent magnetic heads, the following improvements are made. Namely, when  
a first layer conductor pattern 11 is formed on a lower  
20 magnetic layer 25 (see Fig. 9) on a substrate 24, as illustrated in Fig. 10A, a first layer conductor pattern 11' of a second magnetic head, corresponding to a second layer conductor pattern 16 of a first magnetic head, is formed adjacently to the first layer conductor pattern 11 of the  
25 first magnetic head (located on the left end in Fig. 10A) with a slit d therebetween. In other words, the first layer conductor pattern 11' of the second magnetic head has a pattern shape corresponding to that of the second layer conductor pattern 16 of the first magnetic head.  
30 The slit d has a width equal to the pattern width t (see Fig. 10B) of the second layer conductor patterns 16 and 16' formed on the slit d. In the embodiment illustrated in the drawing, the conductor pattern 11 has a spiral shape of two windings in the clockwise direction, and the  
35 conductor pattern 11' has a spiral shape of three windings in the clockwise direction. The first layer conductor patterns 11 and 11' are arranged in this order in a number

corresponding to the number of the magnetic heads (4 in the drawing). As illustrated in Figs. 10B, the second layer conductor patterns 16 and 16' are arranged alternately in an order reverse to the order in the arrangement illustrated in Fig. 10A. These second layer conductor patterns 16 and 16' are formed so as to fill up the slits between the first layer conductor patterns 11 and 11' according to the process as shown in Figs. 7A and 7B. The second layer conductor patterns 16 and 16' (having a width t) are formed on the slits d between the first layer conductor patterns 11 and 11'. Accordingly, the respective magnetic heads are arranged without any slit. By forming the second layer conductor patterns 16 and 16' on the slits between the first layer conductor patterns 11 and 11', there is formed a first plane layer as illustrated in Fig. 7B-(e). The state where up to the second layer conductor patterns are formed is illustrated in the plane view of Fig. 11A.

Third layer conductor patterns 28 and 28' (see Fig. 10C) and fourth layer conductor patterns 40 and 40' (see Fig. 10D) constituting the second plane layer are formed in a manner similar to the above-mentioned manner. In this case, the winding directions of the third layer conductor patterns 28 and 28' and the fourth layer conductor patterns 40 and 40' are reverse to those of the first layer conductor patterns 11 and 11' and the second layer conductor patterns 16 and 16', respectively. Furthermore, the third layer conductor pattern 28 of an odd-numbered magnetic head corresponds to the fourth layer conductor pattern 40' of an even-numbered magnetic head, while the third layer conductor pattern 28' of an even-numbered magnetic head corresponds to the fourth layer conductor pattern 40 of an odd-numbered magnetic head. A second plane layer constructed by the third layer conductor patterns 28 and 28' and the fourth layer conductor patterns 40 and 40' is illustrated in Fig. 11B.

For example, in the case of an odd-numbered

magnetic head, the inner end portion of the first layer conductor pattern 11 is connected to the inner end portion 44 of the third layer conductor pattern 28 through the window 34; the outer end portion thereof is connected to 5 the outer end portion 35 of the second layer conductor pattern 16 by the window 43, and; the inner end portion thereof is connected to the inner end portion 45 of the fourth layer conductor pattern 40 by the window 39. When terminals or the like are connected to the windows 11A and 10 40A on the outer end portions of the first and fourth layer conductor patterns 11 and 40 in the above-mentioned connection state, the respective conductor patterns 11, 16, 28 and 40 are connected in a line to form a coil of 10 windings. Also with respect to an even-numbered magnetic 15 head, a coil of 10 windings is formed in a manner similar to the above-mentioned manner.

Finally, an upper magnetic layer 30 is formed, whereby a multi-track magnetic head including a plurality of magnetic heads arranged in a line without any slit, as 20 illustrated in Fig. 9, is formed.

As will be apparent from the foregoing description, by using the coil-preparing process disclosed by the present invention, a multi-track magnetic head including a plurality of magnetic heads arranged without any slit can 25 be manufactured, and the track density can be increased in a magnetic disc device or the like.

It will readily be understood that a transformer can be constructed by disposing, for example, an annular iron core 61 to spread over two adjacent coils formed according 30 to the steps illustrated in Figs. 11A and 11B, though this feature is not specifically illustrated in the drawing.

As described hereinbefore, according to the present invention, since a flattened filmy multi-layer multi-winding coil can be prepared, the defects described in the introduction part of this specification can be eliminated and 35 the intended objects of the present invention can be attained.

- 13A -

## TABLE OF REFERENCE NUMERALS AND PARTS

<u>Reference Numeral</u>	<u>Part</u>
10	substrate
11	first layer conductor pattern
14	slit
16	second layer conductor pattern
28	third layer conductor pattern
34, 35, 39, 43, 44, 45	windows
40	fourth layer conductor pattern

## CLAIMS

1. A process for the preparation of thin-film coils comprising by forming a first plane coil layer having a flat top face by arranging a plurality of layers of spiral conductor patterns (11, 16) wound in the same direction, adjacently to one another without any slit with the interposition of an insulating layer (13) therebetween on the same plane, forming and laminating on said first plane coil layer a second plane coil layer by arranging a plurality of layers of spiral conductor patterns (28, 40) wound in a direction reverse to the winding direction of said spiral conductor patterns of the first plane coil layer in the same manner as the manner of arranging the spiral conductor patterns of the first plane coil layer, and connecting the conductor patterns in the first plane coil layer to the conductor patterns in the second plane coil layer alternately to form one coil having said conductor patterns thus connected in series.

2. A process for the preparation of film coils according to claim 1 wherein a plurality of first plane coil layers and a plurality of second plane coil layers are laminated alternately and the spiral conductor patterns (11, 16, 28, 40) in every two adjacent plane coil layers are continuously connected in series.

3. A process for the preparation of film coils according to claim 1 wherein a plurality of layers of spiral conductor patterns (11, 16) wound in the same direction with a predetermined taper angle are arranged so that the taper portions of the respective spiral conductor patterns are piled onto each other with the interposition of insulating layer (13) on the same plane, whereby a plane coil layer having a flat top face is formed.

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Fig. 1

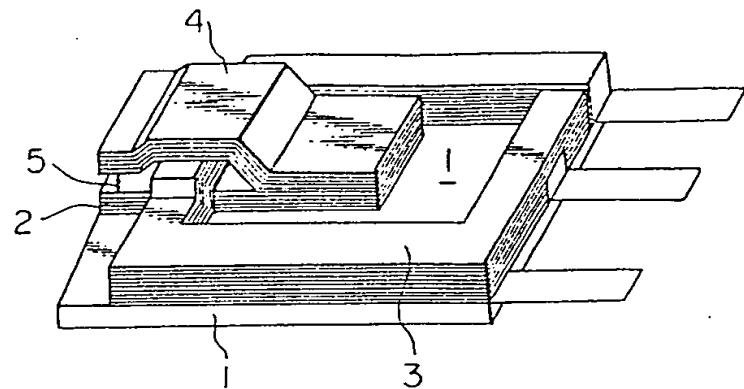


Fig. 2

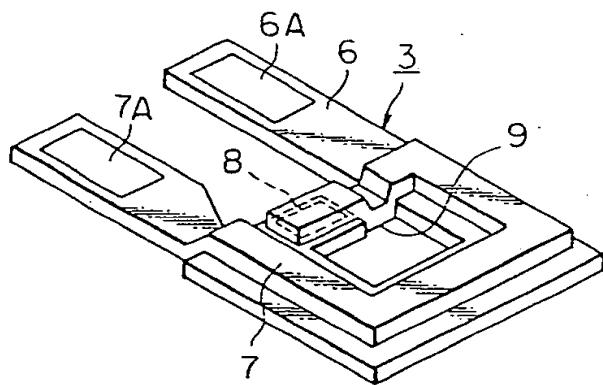


Fig. 3A

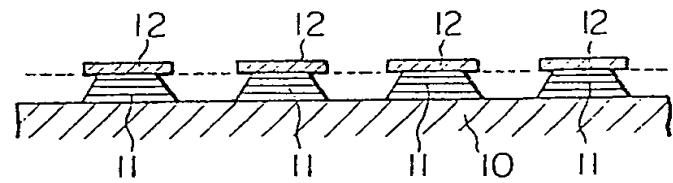


Fig. 3B

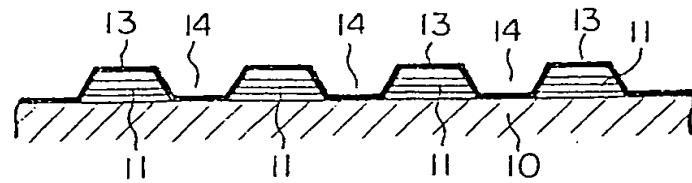


Fig. 3C

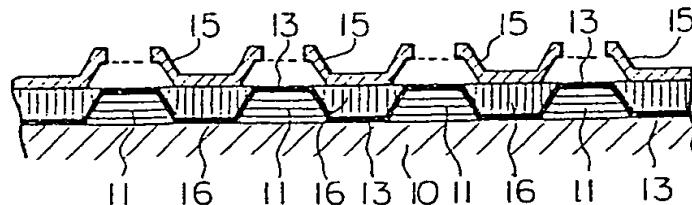
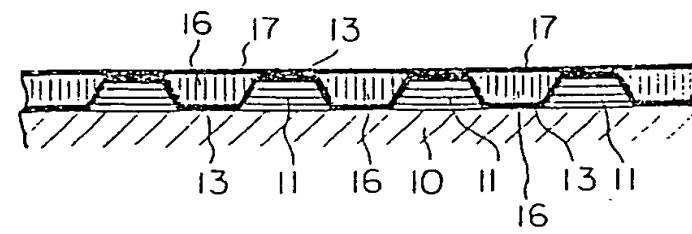


Fig. 3D



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Fig. 4A

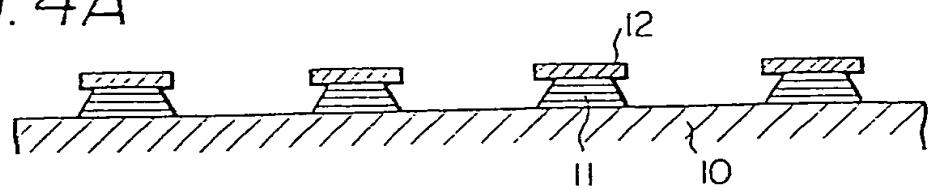


Fig. 4B

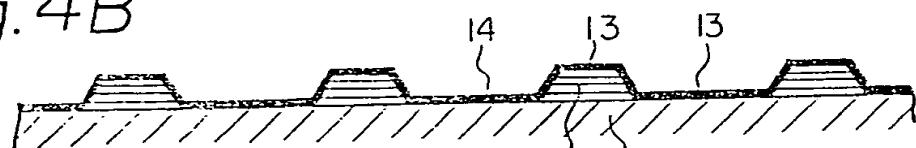


Fig. 4C

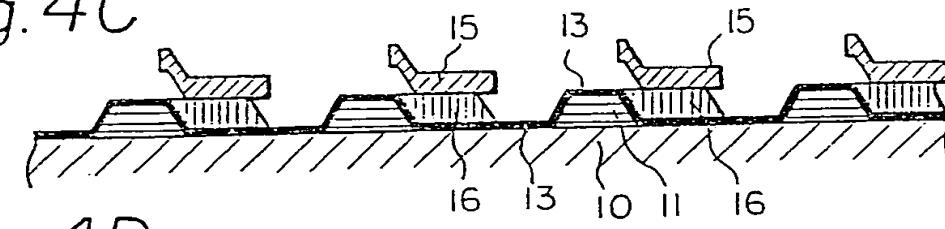


Fig. 4D

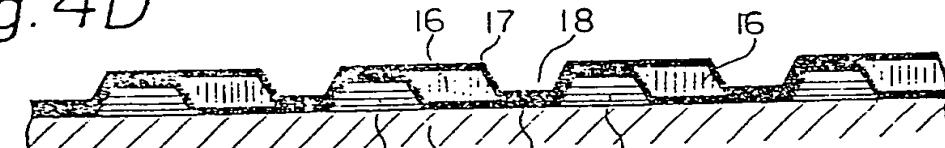


Fig. 4E

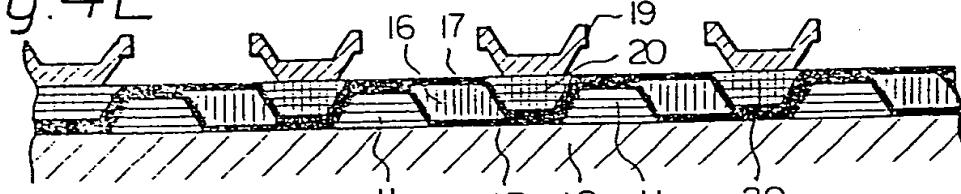


Fig. 4F

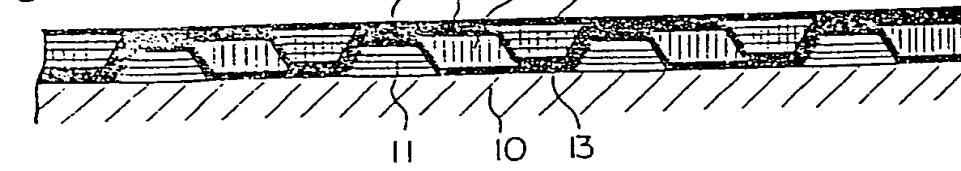


Fig. 4E'

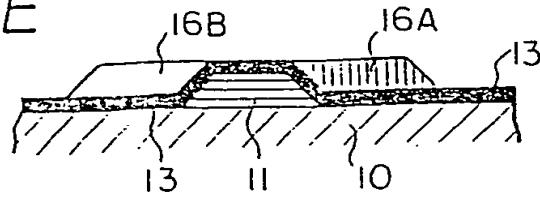


Fig. 5A(a)

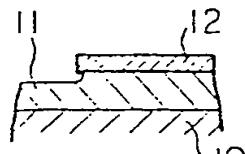


Fig. 5A(b)

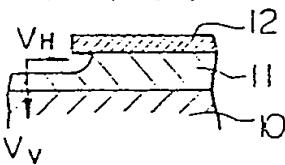


Fig.5A(c)

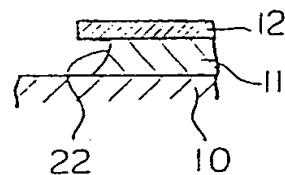


Fig. 5B(a)

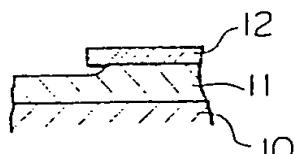


Fig. 5B(b)

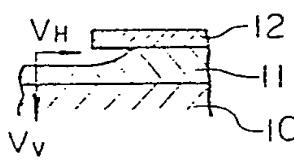


Fig. 5B(c)

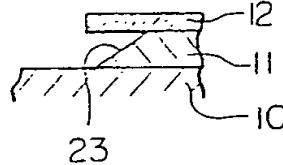


Fig. 6A

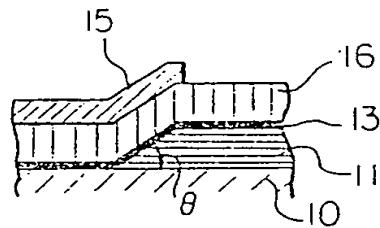


Fig. 6B

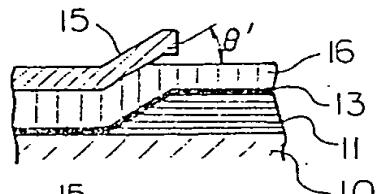
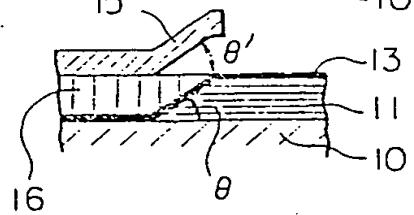


Fig. 6C



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Fig. 7A(a)

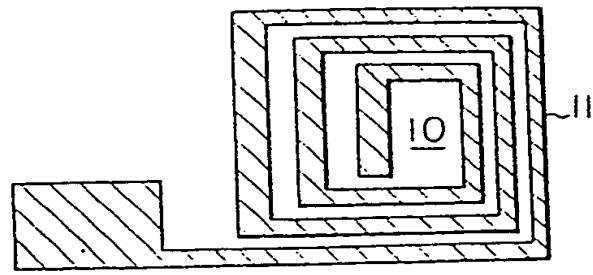


Fig. 7A(b)

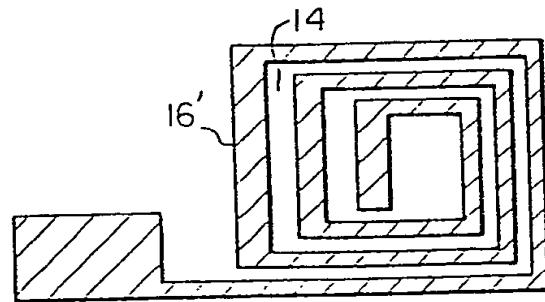


Fig. 7A(c)

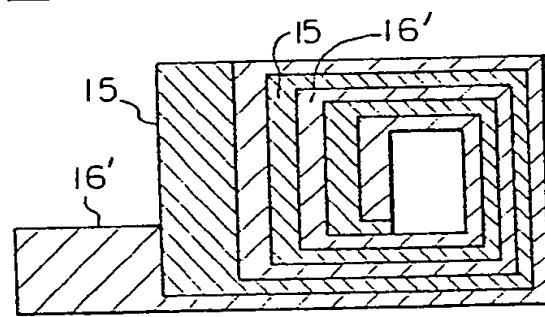


Fig. 7A(d)

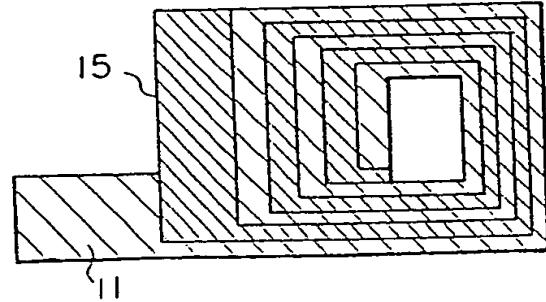


Fig. 7A(e)

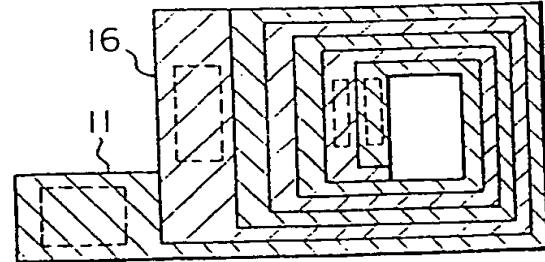


Fig. 7B(a)

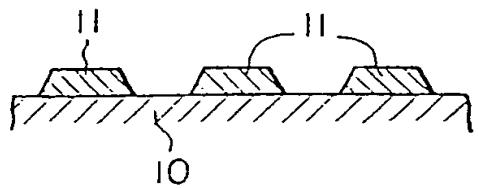


Fig. 7B(b)

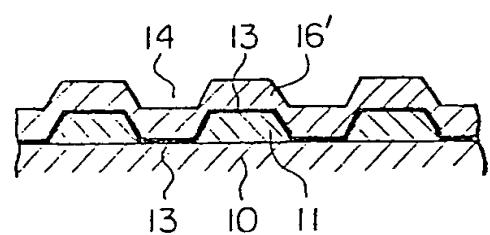


Fig. 7B(c)

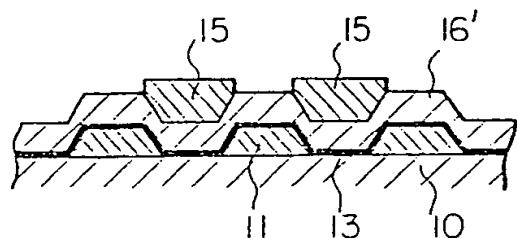


Fig. 7B(d)

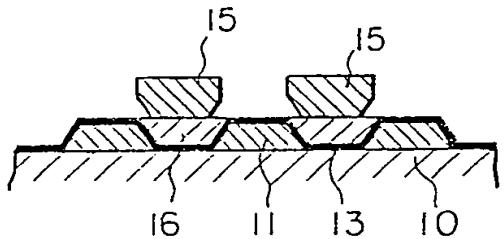
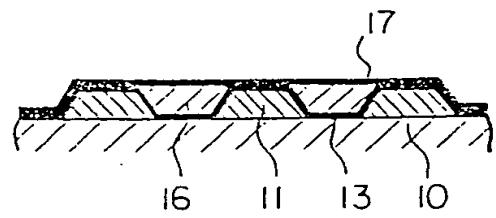


Fig. 7B(e)



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Fig. 8A Fig. 8B Fig. 8C Fig. 8D

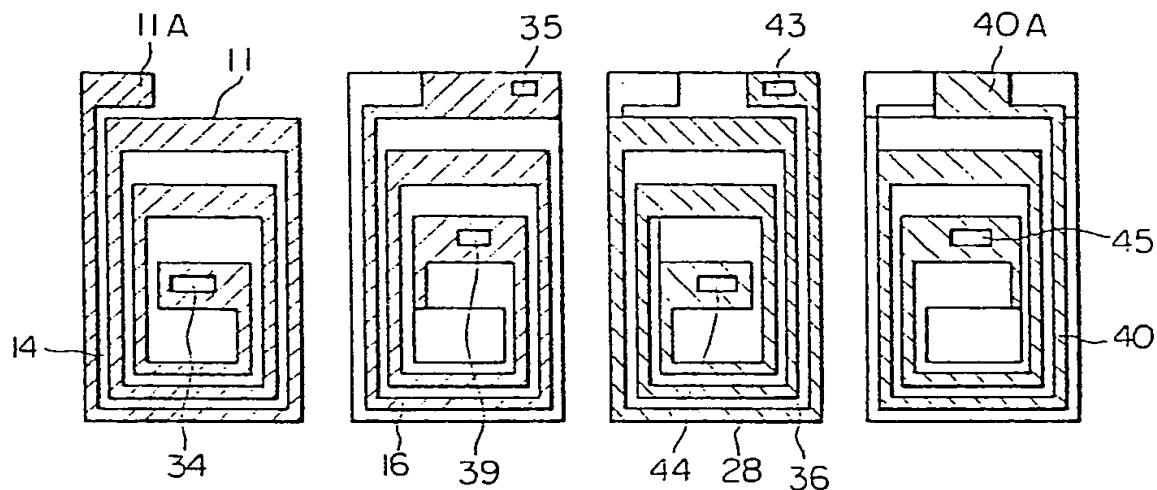
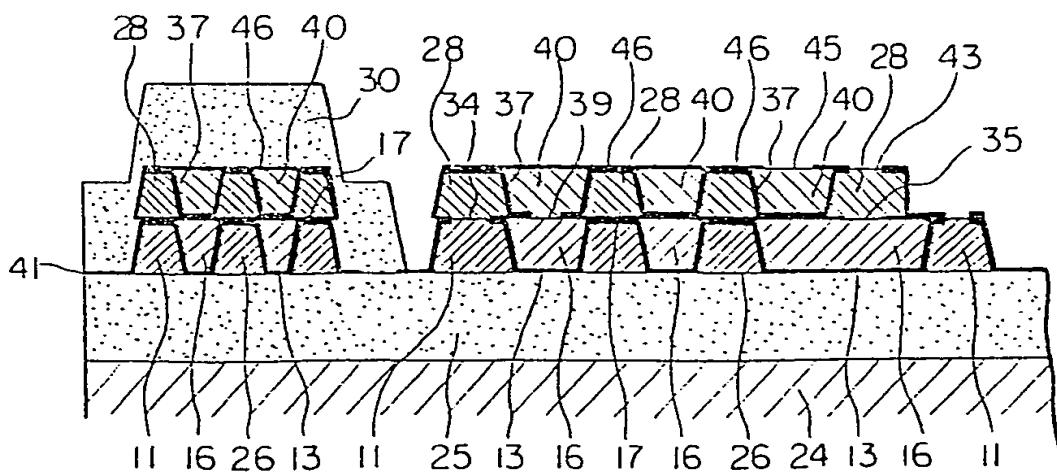


Fig. 9



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Fig. 10A

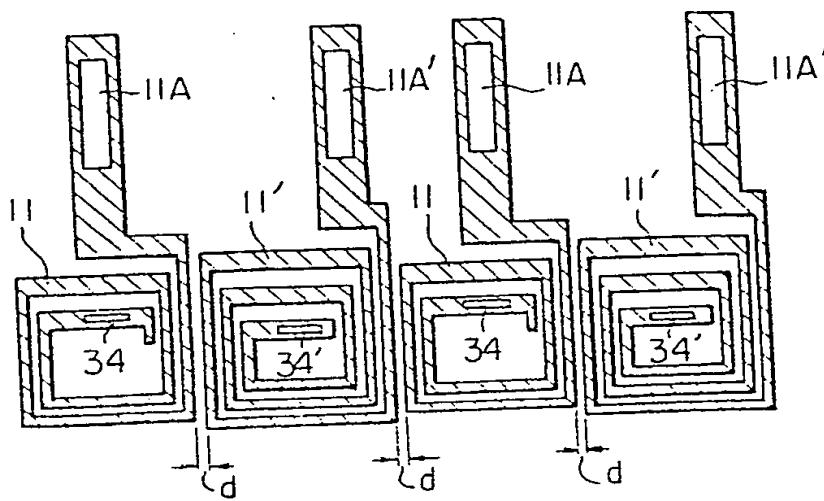


Fig. 10B

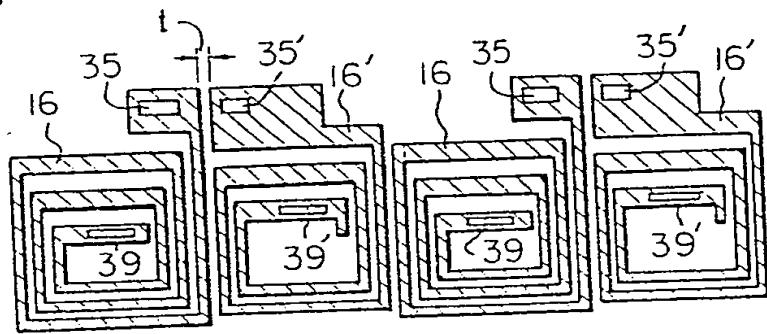


Fig. 10C

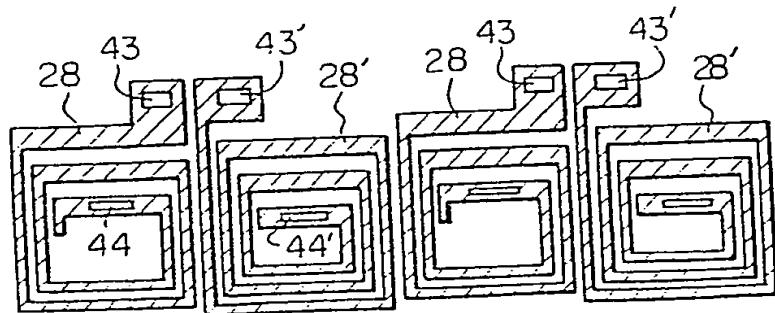
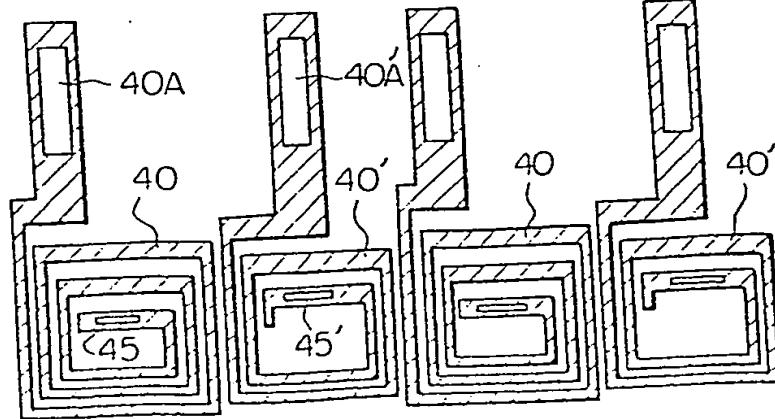


Fig. 10D



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Fig. IIIA

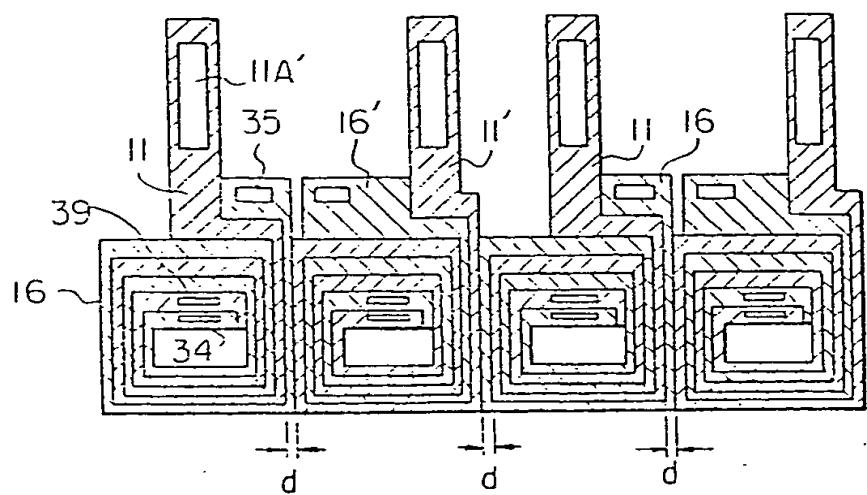
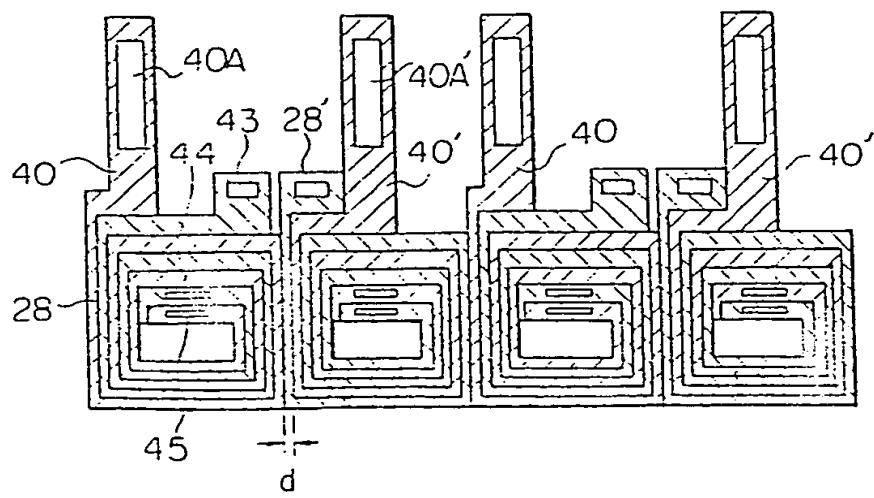


Fig. IIIB



0006959

## INTERNATIONAL SEARCH REPORT

International Application No PCT/JP 78/00049

I. CLASSIFICATION OF SUBJECT MATTER (If several classification symbols apply, indicate all) <sup>1</sup>	
According to International Patent Classification (IPC) or to both National Classification and IPC H01F 41/04, H01F 5/00, G01B 5/20, H05K 1/16	

## II. FIELDS SEARCHED

Classification System	Minimum Documentation Searched <sup>4</sup>	Classification Symbols
I.P.C.	H01F 41/04, H01F 5/00, H05K 1/16, H01L 21/90, G01B 5/20	

Documentation Searched other than Minimum Documentation  
to the Extent that such Documents are Included in the Fields Searched<sup>5</sup>

Jitsuyo Shinan Koho 1945 - 1978  
Kokai Jitsuyo Shinan Koho 1971 - 1978

III. DOCUMENTS CONSIDERED TO BE RELEVANT<sup>14</sup>

Category <sup>6</sup>	Citation of Document <sup>15</sup> with indication, where appropriate, of the relevant passages <sup>17</sup>	Relevant to Claim No. <sup>18</sup>
A	JP, A, 49-6448, 1974-1-21 Citizen Watch Co.Ltd.	1-3
A	JP, Bl, 48-32863, 1973-10-9 Hitachi, Ltd.	1-3
A	US, A, 3,385,999, 1968-5-28 Westinghouse Electric Corp.	1-3
A	IBM Technical Disclosure Bulletin Vol.13 n 6 November 1970 p1567	1-3
A	JP, Bl, 49-39551, 1974-10-26 Nippon Electric Co. Ltd.	3

• Special categories of cited documents:<sup>19</sup>

- "A" document defining the general state of the art
- "E" earlier document but published on or after the international filing date
- "L" document cited for special reason other than those referred to in the other categories
- "O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date on or after the priority date claimed

"T" later document published on or after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance

## IV. CERTIFICATION

Date of the Actual Completion of the International Search<sup>20</sup>

05.03.79

Date of Mailing of this International Search Report<sup>21</sup>

12.03.79

International Searching Authority<sup>22</sup>

Japanese Patent Office

Signature of Authorized Officer<sup>23</sup>

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